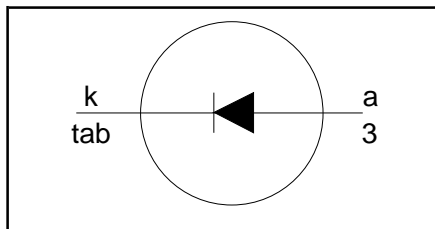


# Rectifier diode ultrafast, low switching loss

**BYC8B-600****FEATURES**

- Extremely fast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching losses in associated MOSFET

**SYMBOL****QUICK REFERENCE DATA**

$$V_R = 600 \text{ V}$$

$$V_F \leq 1.85 \text{ V}$$

$$I_{F(AV)} = 8 \text{ A}$$

$$t_{rr} = 19 \text{ ns (typ)}$$

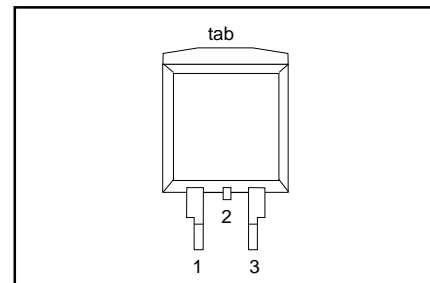
**APPLICATIONS**

- Active power factor correction
- Half-bridge lighting ballasts
- Half-bridge/ full-bridge switched mode power supplies.

The BYC8B-600 is supplied in the SOT404 surface mounting package.

**PINNING**

PIN	DESCRIPTION
1	no connection
2	cathode <sup>1</sup>
3	anode
tab	cathode

**SOT404****LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	Peak repetitive reverse voltage	$T_{mb} \leq 110^\circ\text{C}$ $\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 82^\circ\text{C}$ $\delta = 0.5$ ; with reapplied $V_{RRM(max)}$ ; $T_{mb} \leq 82^\circ\text{C}$ $t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ sinusoidal; $T_j = 150^\circ\text{C}$ prior to surge with reapplied $V_{RWM(max)}$	-	600	V
$V_{RWM}$	Crest working reverse voltage		-	600	V
$V_R$	Continuous reverse voltage		-	500	V
$I_{F(AV)}$	Average forward current		-	8	A
$I_{FRM}$	Repetitive peak forward current		-	16	A
$I_{FSM}$	Non-repetitive peak forward current.	$T_{mb} \leq 82^\circ\text{C}$ $t = 10 \text{ ms}$ $t = 8.3 \text{ ms}$ sinusoidal; $T_j = 150^\circ\text{C}$ prior to surge with reapplied $V_{RWM(max)}$	-	55	A
			-	60	A
$T_{stg}$	Storage temperature		-40	150	$^\circ\text{C}$
$T_j$	Operating junction temperature		-	150	$^\circ\text{C}$

**THERMAL RESISTANCES**

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-mb}$	Thermal resistance junction to mounting base	minimum footprint, FR4 board	-	-	2.2	K/W
$R_{th j-a}$	Thermal resistance junction to ambient		-	50	-	K/W

<sup>1</sup> it is not possible to make connection to pin 2 of the SOT404 package

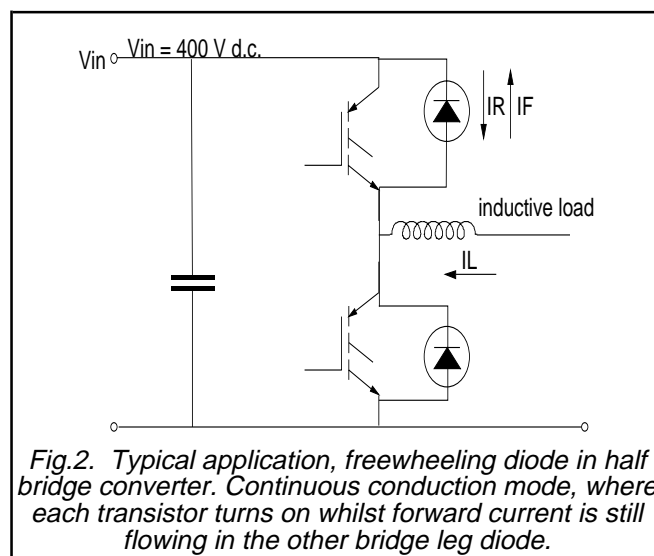
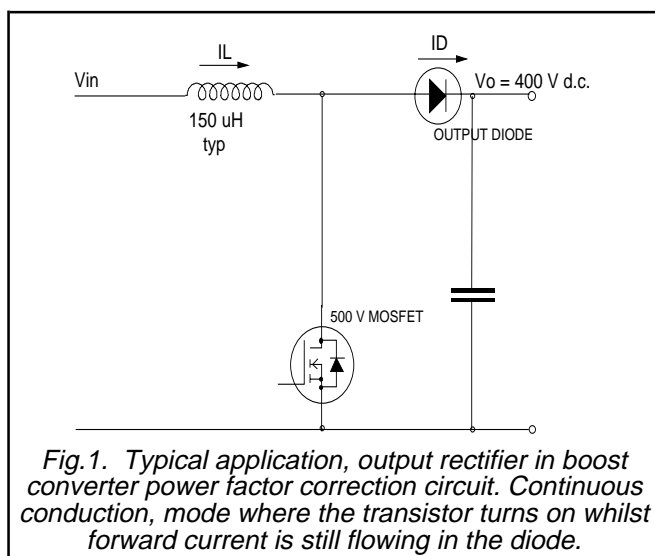
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## ELECTRICAL CHARACTERISTICS

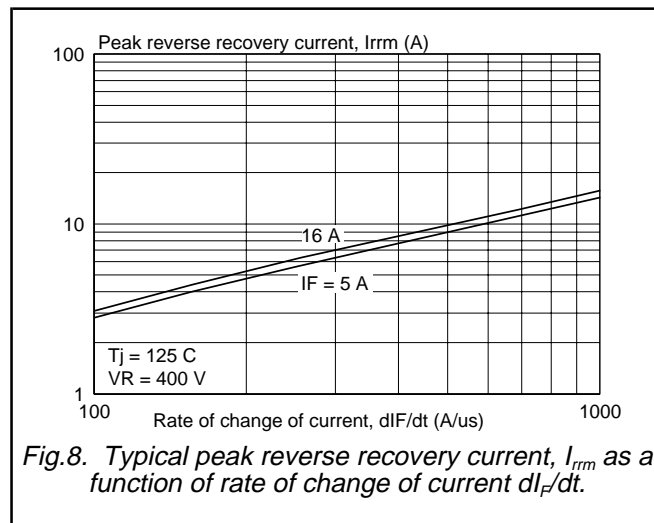
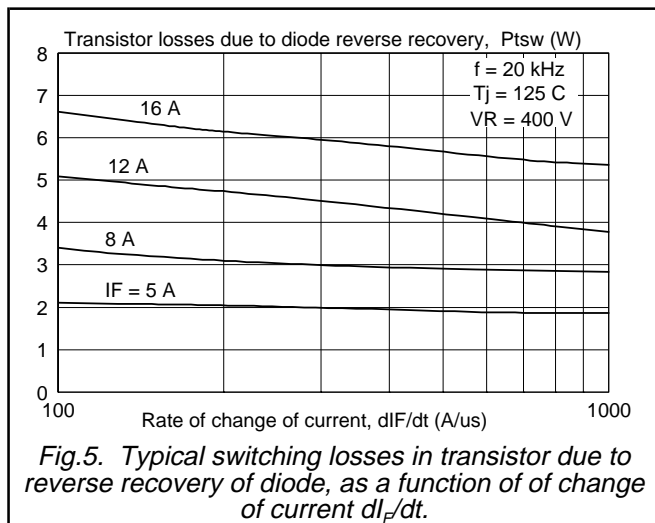
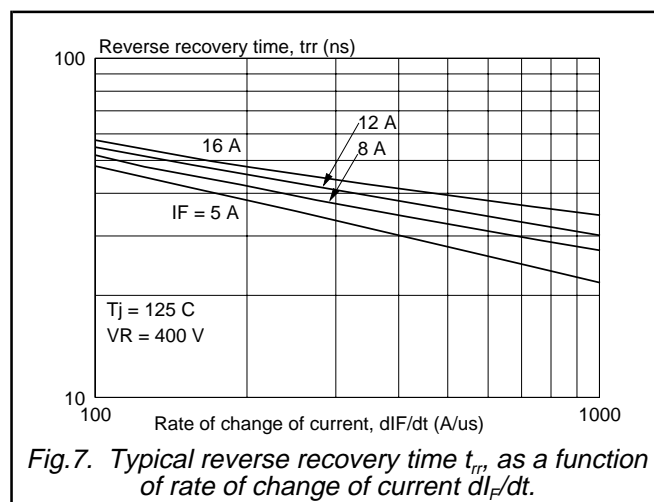
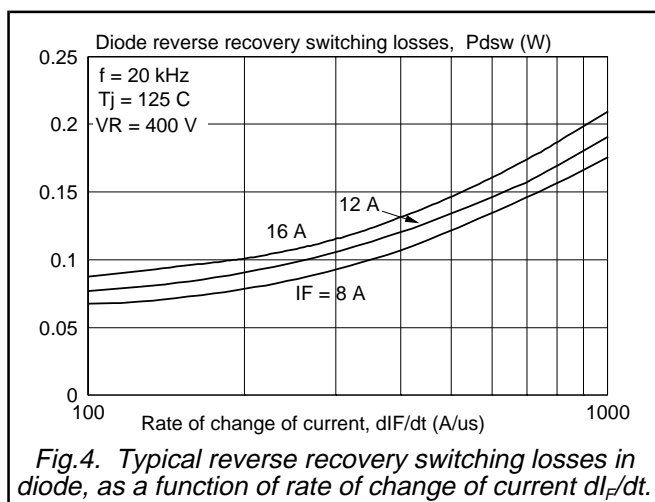
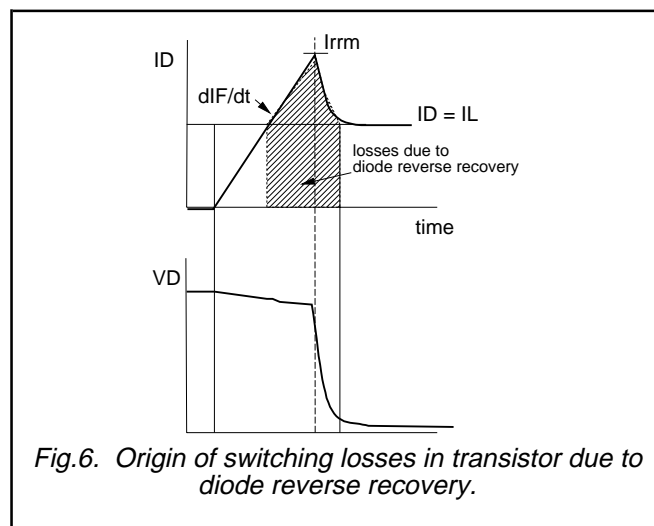
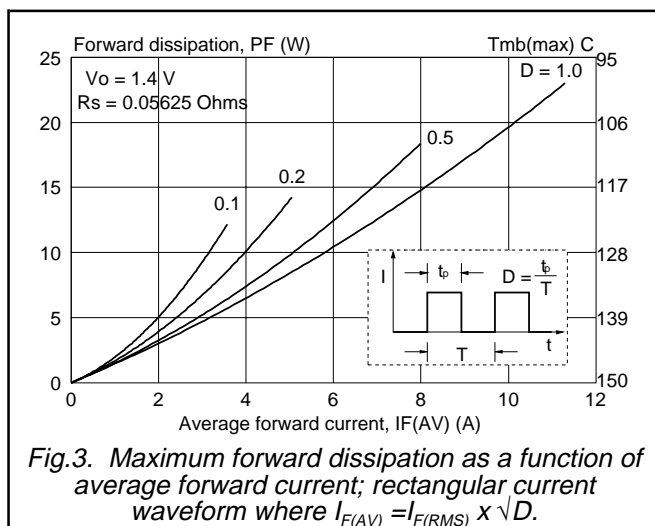
 $T_j = 25\text{ }^{\circ}\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 8\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	-	1.4	1.85	V
		$I_F = 16\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	-	1.7	2.3	V
$I_R$	Reverse current	$I_F = 8\text{ A}$ ; $V_R = 600\text{ V}$	-	2.0	2.8	V
		$V_R = 500\text{ V}$ ; $T_j = 100\text{ }^{\circ}\text{C}$	-	9	150	$\mu\text{A}$
$t_{rr}$	Reverse recovery time	$I_F = 1\text{ A}$ ; $V_R = 30\text{ V}$ ; $dI_F/dt = 50\text{ A}/\mu\text{s}$	-	30	52	ns
$t_{rr}$	Reverse recovery time	$I_F = 8\text{ A}$ ; $V_R = 400\text{ V}$ ; $dI_F/dt = 500\text{ A}/\mu\text{s}$	-	19	-	ns
$t_{rr}$	Reverse recovery time	$I_F = 8\text{ A}$ ; $V_R = 400\text{ V}$ ; $dI_F/dt = 500\text{ A}/\mu\text{s}$ ; $T_j = 125\text{ }^{\circ}\text{C}$	-	32	40	ns
$I_{rrm}$	Peak reverse recovery current	$I_F = 8\text{ A}$ ; $V_R = 400\text{ V}$ ; $dI_F/dt = 50\text{ A}/\mu\text{s}$ ; $T_j = 125\text{ }^{\circ}\text{C}$	-	1.5	5.5	A
$I_{rrm}$	Peak reverse recovery current	$I_F = 8\text{ A}$ ; $V_R = 400\text{ V}$ ; $dI_F/dt = 500\text{ A}/\mu\text{s}$ ; $T_j = 125\text{ }^{\circ}\text{C}$	-	9.5	12	A
$V_{fr}$	Forward recovery voltage	$I_F = 10\text{ A}$ ; $dI_F/dt = 100\text{ A}/\mu\text{s}$	-	8	10	V



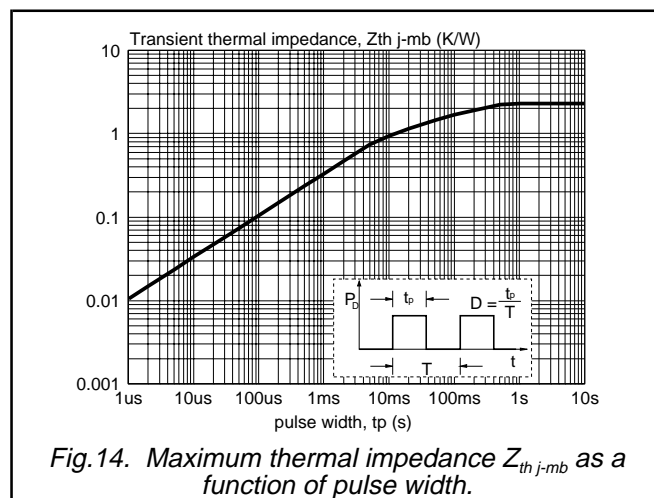
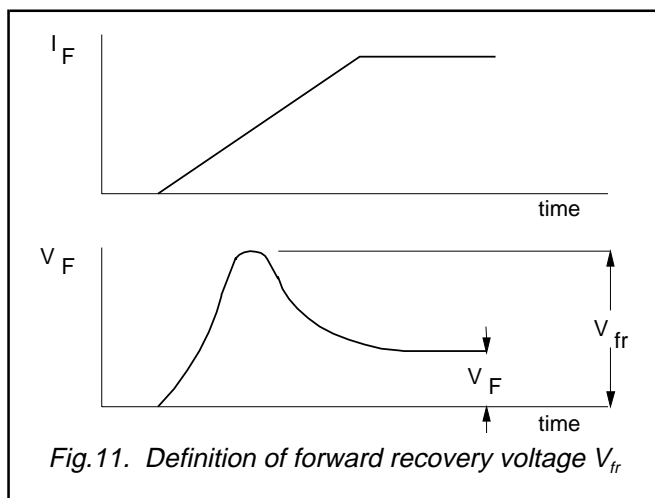
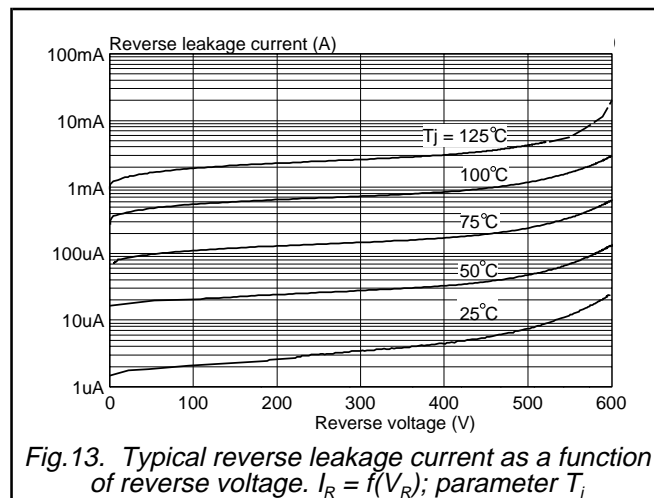
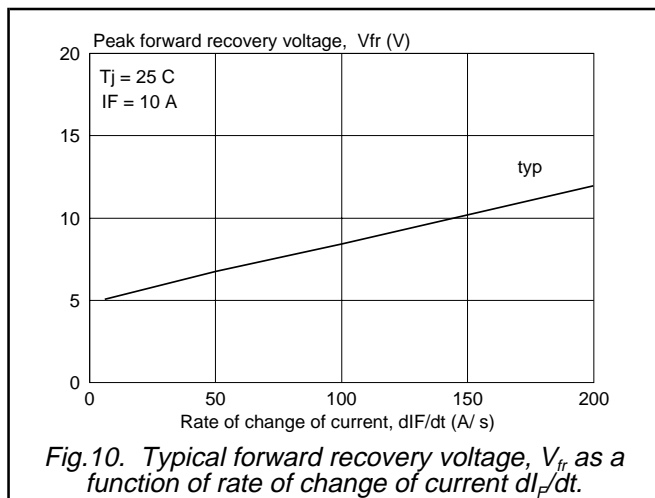
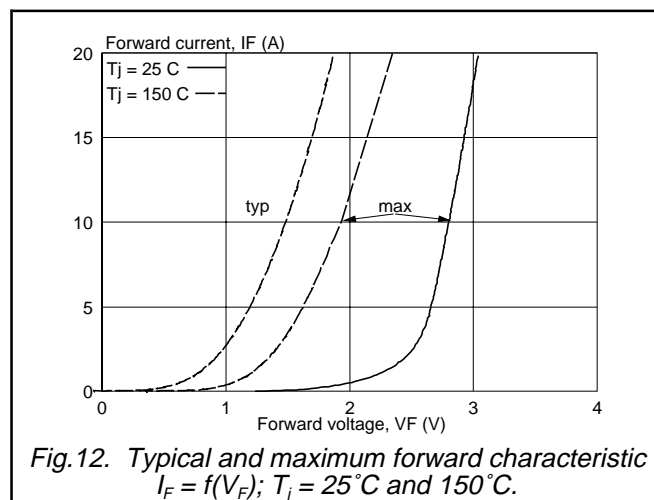
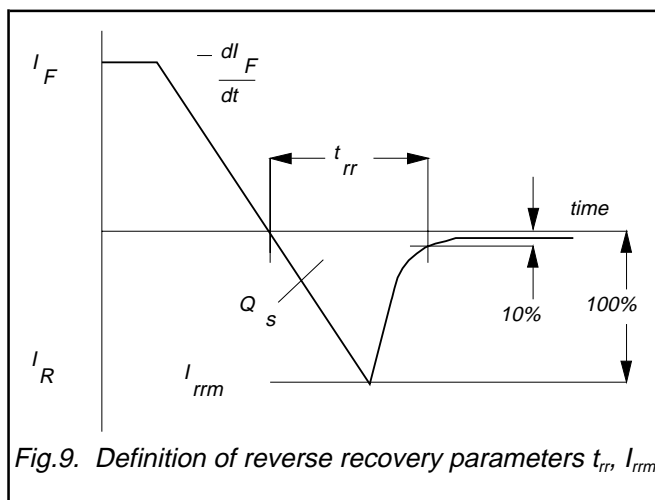
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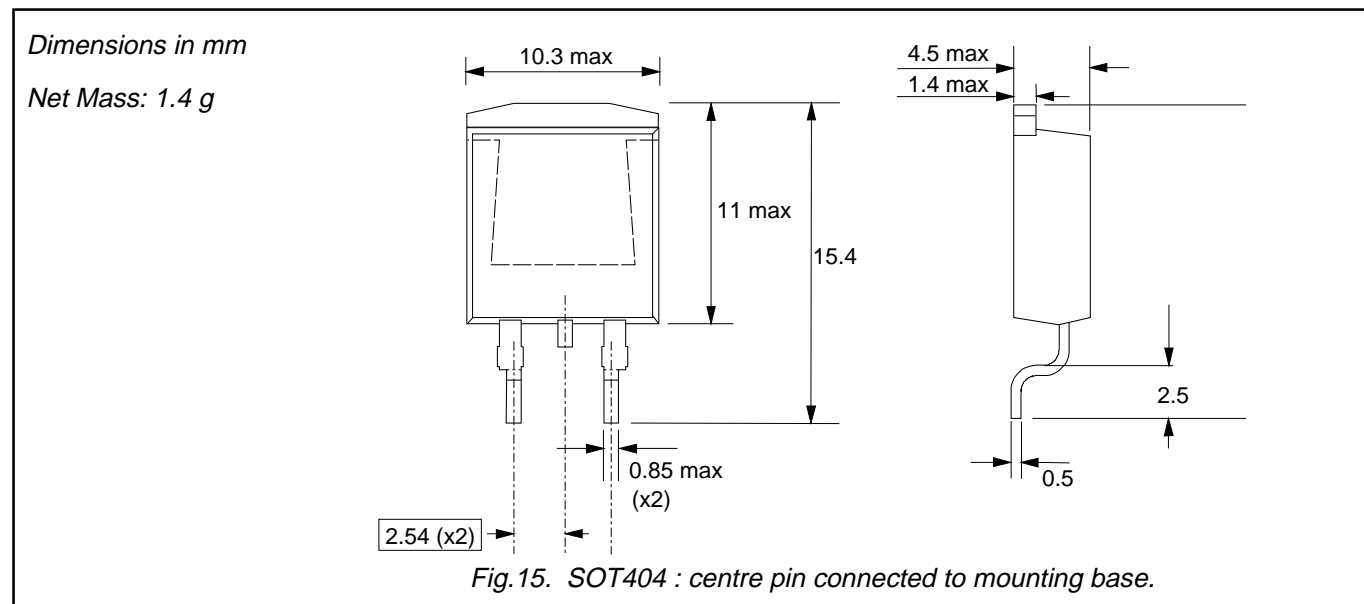
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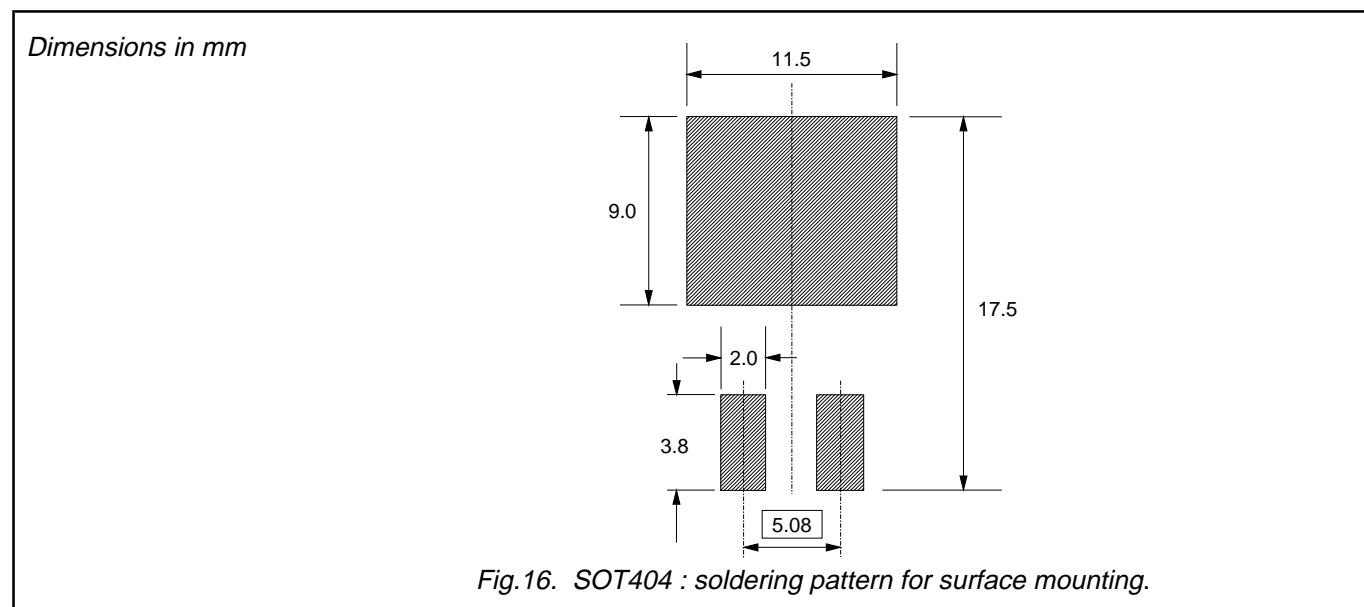
# Rectifier diode ultrafast, low switching loss

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## MECHANICAL DATA



## MOUNTING INSTRUCTIONS



### Notes

1. Epoxy meets UL94 V0 at 1/8".

## Rectifier diode ultrafast, low switching loss

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### DEFINITIONS

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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